TOSHIBA Transistor Silicon PNP Triple Diffused Type

# 2SB1375

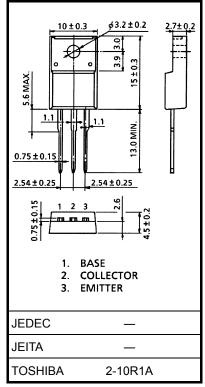
#### Audio Frequency Power Amplifier

Unit: mm

- Low saturation voltage: VCE (sat) = -1.5 V (max) (I<sub>C</sub> = -2 A, I<sub>B</sub> = -0.2 A)
- High power dissipation:  $P_C = 25 \text{ W} (T_c = 25^{\circ}C)$
- Collector metal (fin) is covered with mold resin
- Complementary to 2SD2012

### Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	-60	V	
Collector-emitter voltage		V <sub>CEO</sub>	-60	V	
Emitter-base voltage		V <sub>EBO</sub>	-7	V	
Collector current		Ι <sub>C</sub>	-3	А	
Base current		Ι <sub>Β</sub>	-0.5	А	
Collector power dissipation	Ta = 25°C	Pc	2.0	W	
	Tc = 25°C	FC	25		
Junction temperature		Тј	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to

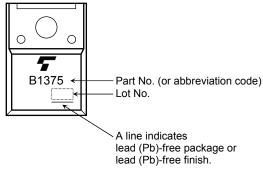
decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

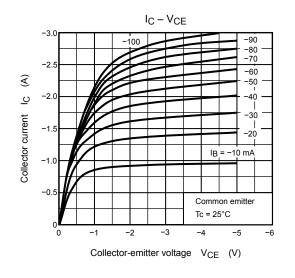
Electrical Characteristics (Tc = 25°C)

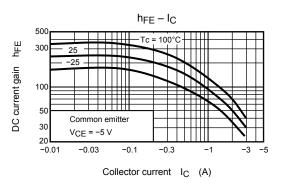
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -60 \text{ V}, \text{ I}_{E} = 0$	_	_	-10	μA
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -7 V, I_C = 0$	_	_	-10	μA
Collector-emitter breakdown voltage	V (BR) CEO	I <sub>C</sub> = -50 mA, I <sub>B</sub> = 0	-60	_	_	V
DC current gain	h <sub>FE (1)</sub>	$V_{CE} = -5 V, I_C = -0.5 A$	100	_	320	
	h <sub>FE (2)</sub>	$V_{CE} = -5 V, I_C = -2 A$	15	_	_	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = -2 A, I <sub>B</sub> = -0.2 A	_	-1.0	-1.5	V
Base-emitter voltage	V <sub>BE</sub>	$V_{CE} = -5 V, I_C = -0.5 A$	_	-0.75	-1.0	V
Transition frequency	f <sub>T</sub>	$V_{CE} = -5 V, I_C = -0.5 A$	_	9	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = −10 V, I <sub>E</sub> = 0, f = 1 MHz	_	50	_	pF

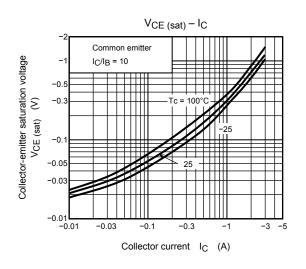
# Marking

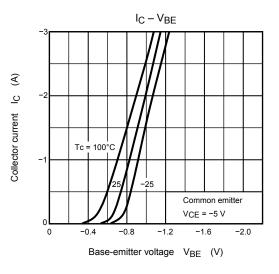


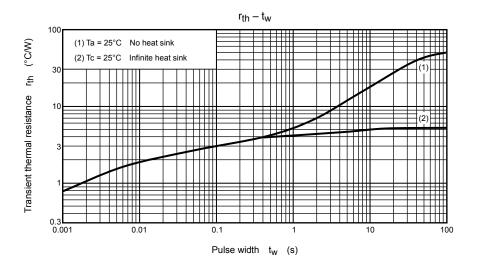
# **TOSHIBA**



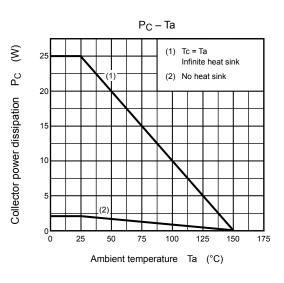








Safe Operating Area -10 IC max (pulsed)\* ms⁴  $\overline{\mathsf{A}}$ IC max (continuous) Collector current I<sub>C</sub> 10 ms 100 ms\* DC operation Tc = 25°C -0.5 \*: Single nonrepetitive pulse Tc = 25°C -0.3 Curves must be derated linearly with increase in temperature VCEO max -0.1 -3 -5 -10 -30 -50 -100 -200 -1 Collector-emitter voltage  $V_{CE}$  (V)



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